



DMNH6021SPSQ

POWERDI

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
	23mΩ @ V _{GS} = 10V	55A
60V	$28m\Omega @ V_{GS} = 4.5V$	48A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- **Driving Solenoids**
- **Driving Relays**
- **Power Management Functions**

Features and Benefits

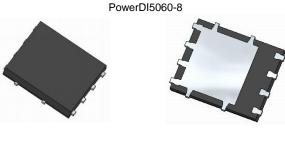
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application

60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

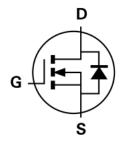
Mechanical Data

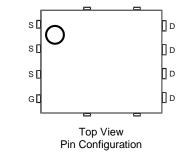
- Case: PowerDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



Top View

Bottom View





Internal Schematic

Ordering Information (Note 5)

	Part Number	Case	Packaging		
	DMNH6021SPSQ-13	PowerDI5060-8	2,500 / Tape & Reel		
Notes:	es: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.				

Pin1

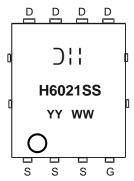
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

A dutomotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



D!! = Manufacturer's Marking H6021SS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 16 = 2016) WW = Week (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	60	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 8)	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ID	55 39	A
Maximum Continuous Body Diode Forward Current (Note 8)	Is	55	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	88	A
Avalanche Current, L = 0.1mH (Note 9)		I _{AS}	35	A
Avalanche Energy, L = 0.1mH (Note 9)		E _{AS}	64	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.6	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ ext{ heta}JA}$	96	°C/W
Total Power Dissipation (Note 7)	T _A = +25°C	PD	3.0	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	$R_{ ext{ heta}JA}$	50	°C/W
Total Power Dissipation (Note 8)	T _C = +25°C	PD	53	W
Thermal Resistance, Junction to Case (Note 8)		$R_{\theta JC}$	1.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

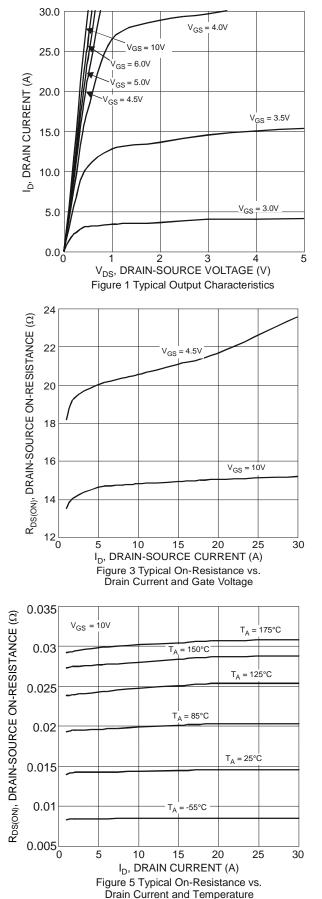
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 10)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	-	-	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1	μA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 10)							
Gate Threshold Voltage	V _{GS(TH)}	1	-	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		-	12	23	mΩ	$V_{GS} = 10V, I_D = 12A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	18	28		V _{GS} = 4.5V, I _D = 12A	
Diode Forward Voltage	V _{SD}	-	0.75	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 11)	•						
Input Capacitance	Ciss	-	1,016	-		$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	-	153	-	pF		
Reverse Transfer Capacitance	C _{rss}	-	76.8	-			
Gate Resistance	R _g	-	2.5	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	-	9.5	-		V _{DS} = 30V, I _D = 20A	
Total Gate Charge (V _{GS} = 10V)	Qg	-	19.7	-	nC		
Gate-Source Charge	Q _{gs}	-	3.6	-	no		
Gate-Drain Charge	Q _{gd}	-	4.8	-			
Turn-On Delay Time	t _{D(ON)}	-	4.2	-			
Turn-On Rise Time	t _R	-	13	-	-	$\label{eq:VDD} \begin{array}{l} V_{DD}=30V, \ V_{GS}=10V, \\ I_{D}=10A, \ R_{g}=4.7\Omega \end{array}$	
Turn-Off Delay Time	t _{D(OFF)}	-	27.5	-	ns		
Turn-Off Fall Time	t _F	-	15.3	-			
Body Diode Reverse Recovery Time	t _{RR}	-	20.8	-	ns		
Body Diode Reverse Recovery Charge	Q _{RR}	-	13.9	-	nC	— I _F = 20A, di/dt = 100A/μs	

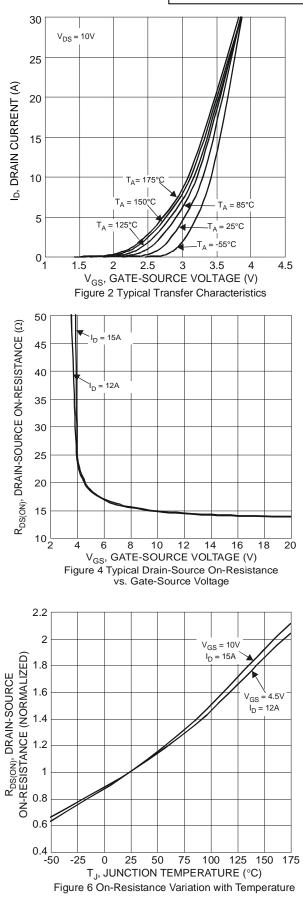
Notes:

6. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
7. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
8. Thermal resistance from junction to soldering point (on the exposed drain pad).
9. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
10. Short duration pulse test used to minimize self-heating effect.
11. Guaranteed by design. Not subject to product testing.



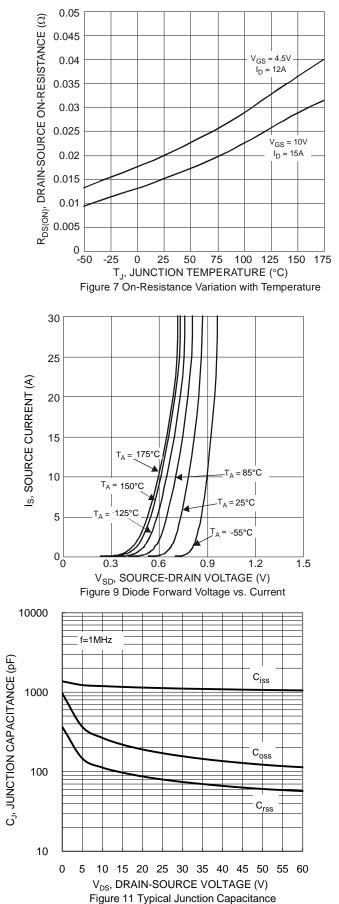


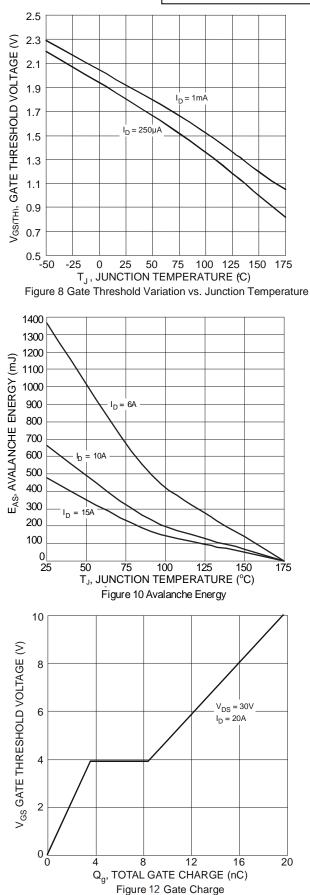






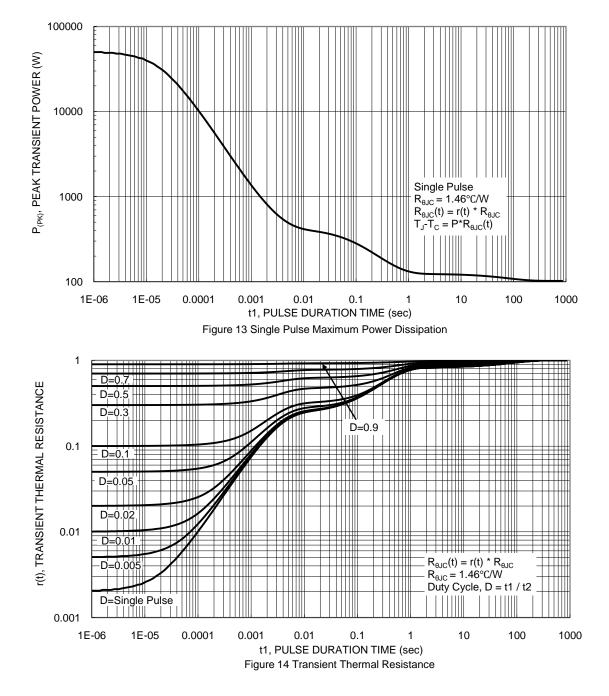






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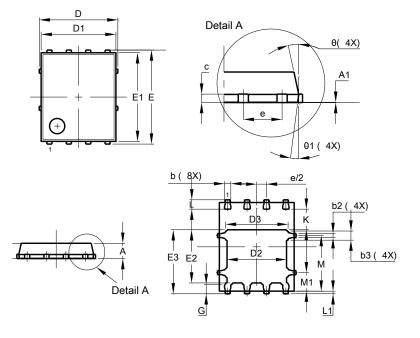




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

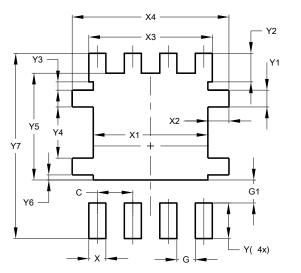


	PowerDI5060-8						
Dim	Min	Max	Тур				
Α	0.90	1.10	1.00				
A1	0.00	0.05	-				
b	0.33	0.51	0.41				
b2	0.200	0.350	0.273				
b3	0.40	0.80	0.60				
С	0.230	0.330	0.277				
D		5.15 BSC					
D1	4.70	5.10	4.90				
D2	3.70	4.10	3.90				
D3	3.90	4.10					
E	(6.15 BSC	,				
E1	5.60	6.00	5.80				
E2	3.28	3.68	3.48				
E3	3.99	4.39	4.19				
е		1.27 BSC					
G	0.51	0.71	0.61				
К	0.51	-	-				
L	0.51	0.71	0.61				
L1	0.100	0.200	0.175				
М	3.235	4.035	3.635				
M1	1.00	1.40	1.21				
Θ	10º	12º	11º				
Θ1	6º	8º	7°				
AI	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)				
С	1.270				
G	0.660				
G1	0.820				
Х	0.610				
X1	4.100				
X2	0.755				
X3	4.420				
X4	5.610				
Y	1.270				
Y1	0.600				
Y2	1.020				
Y3	0.295				
Y4	1.825				
Y5	3.810				
Y6	0.180				
Y7	6.610				



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